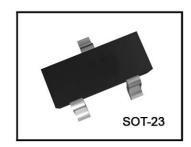


FMMT591

FEATURES

* Low Equivalent on resistance $R_{CE(sat)}$ =355m Ω at 1A*

COMPLEMENTARY TYPE- FMMT491 PARTMARKING DETAIL - 591



• ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-5	V
Peak Pulse Current	I _{CM}	-2	Α
Continuous Collector Current	Ic	-1	Α
Base Current	I _B	-200	mA
Power Dissipation at T _{amb} =25°C	P _{tot}	500	mW
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C

• ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-80		V	I_{C} =-100 μ A, I_{E} =0
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-60		V	I _C =-10mA, I _B =0*
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5		V	I_{E} =-100 μ A, I_{C} =0
Collector Cut-Off Current	I _{CBO}		-100	nA	V _{CB} =-60V
Emitter Cut-Off Current	I _{EBO}		-100	nA	$V_{EB}=-4V$, $I_{C}=0$
Collector-Emitter Cut-Off Current	I _{CES}		-100	nA	V _{CES} =-60V
Collector-Emitter Saturation Voltage	V _{CE(sat)}		-0.3 -0.6	V V	I_{C} =-500mA, I_{B} =-50mA* I_{C} =-1A, I_{B} =-100mA*
Base-Emitter Saturation Voltage	V _{BE(sat)}		-1.2	V	I _C =-1A, I _B =-100mA*
Base-Emitter Turn-on Voltage	V _{BE(on)}		-1.0	V	I _C =-1A, V _{CE} =-5V*
Static Forward Current Transfer Ratio	h _{FE}	100 100 80 15	300		I _C =-1mA, V _{CE} =-5V* I _C =-500mA, V _{CE} =-5V* I _C =-1A, V _{CE} =-5V* I _C =-2A, V _{CE} =-5V*
Transition Frequency	f _T	150		MHz	I _C =-50mA, V _{CE} =-10V f=100MHz
Output Capacitance	C _{obo}		10	pF	V _{CB} =-10V, f=1MHz

^{*}Measured under pulsed conditions. Pulse width=300 μ s. Duty cycle \leq 2%

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Conscious Products Begin With Conscious People

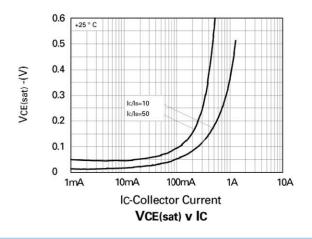


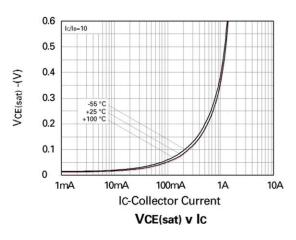


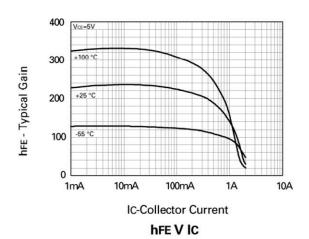


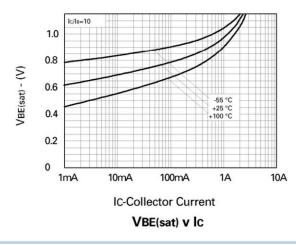
FMMT591

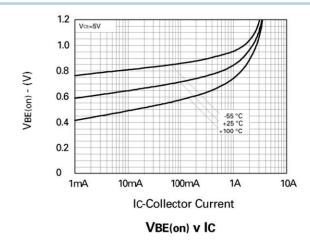
TYPICAL CHARACTERISTICS

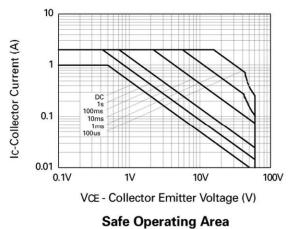












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